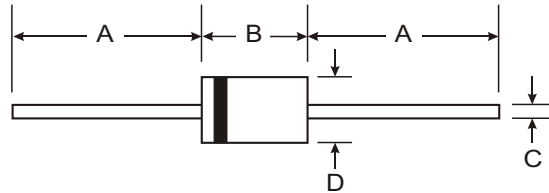


Features

- Glass Passivated Die Construction
- Diffused Junction
- Super-Fast Switching for High Efficiency
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 30A Peak
- Low Reverse Leakage Current
- Plastic Material: UL Flammability Classification Rating 94V-0



Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Marking: Type Number
- Weight: 0.3 grams (approx.)
- Mounting Position: Any

DO-41		
Dim	Min	Max
A	25.40	—
B	4.06	5.21
C	0.71	0.864
D	2.00	2.72
All Dimensions in mm		

Maximum Ratings and Electrical Characteristics @ T_A = 25°C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

Characteristic	Symbol	SF10 AG	SF10 BG	SF10 CG	SF10 DG	SF10 FG	SF10 GG	SF10 HG	SF10 JG	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	150	200	300	400	500	600	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	105	140	210	280	350	420	V
Average Rectified Output Current @ T _A = 75°C (Note 1)	I _O	1.0								A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load (JEDEC Method)	I _{FSM}	30								A
Forward Voltage @ I _F = 1.0A	V _{FM}	0.95				1.3		1.5		V
Peak Reverse Current @ T _A = 25°C at Rated DC Blocking Voltage @ T _A = 100°C	I _{RM}	10 100								μA
Reverse Recovery Time (Note 3)	t _{rr}	35				40		50		ns
Typical Junction Capacitance (Note 2)	C _j	75						50		pF
Thermal Resistance Junction to Ambient	R _{θJA}	75								K/W
Operating and Storage Temperature Range	T _j , T _{STG}	-65 to +150								°C

- Notes:
1. Valid provided that leads are maintained at ambient temperature at a distance of 9.5mm from the case.
 2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.
 3. Measured with I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A. (See Figure 5)

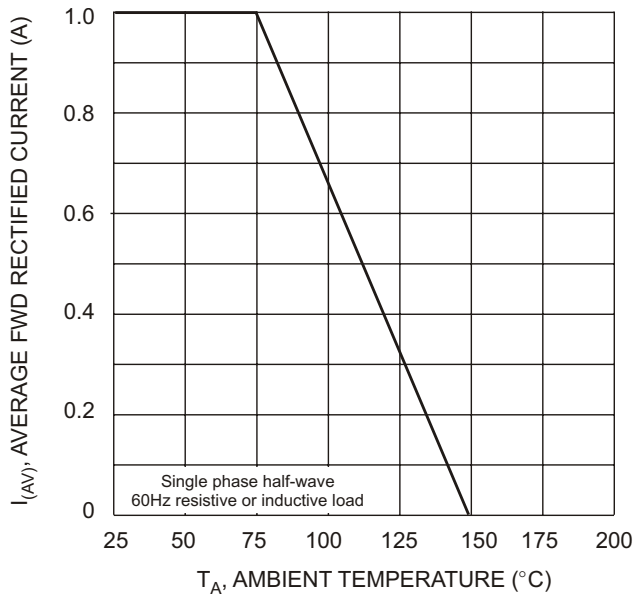


Fig. 1 Forward Current Derating Curve

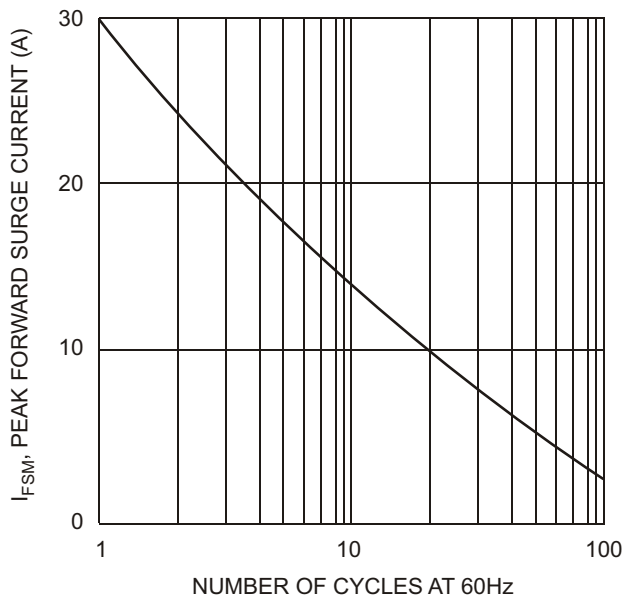
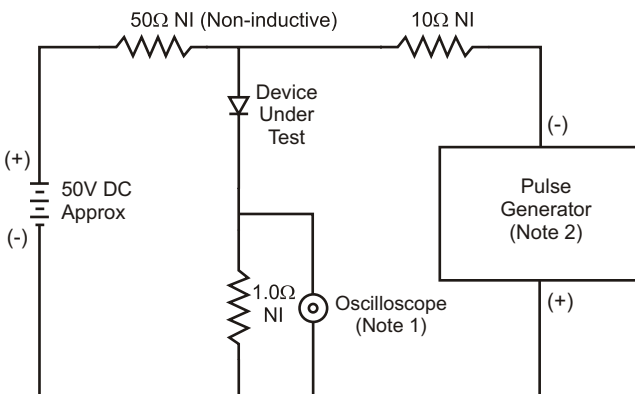


Fig. 3 Peak Forward Surge Current



- Notes:
 1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
 2. Rise Time = 10ns max. Input Impedance = 50Ω.

Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

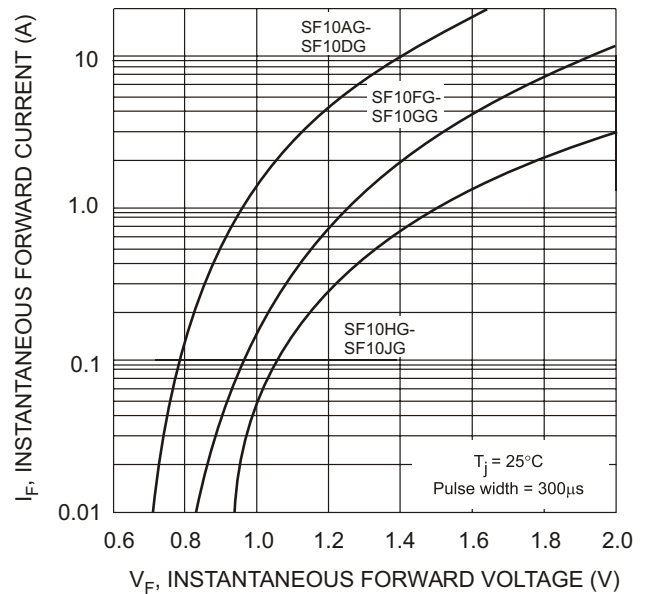


Fig. 2 Typical Forward Characteristics

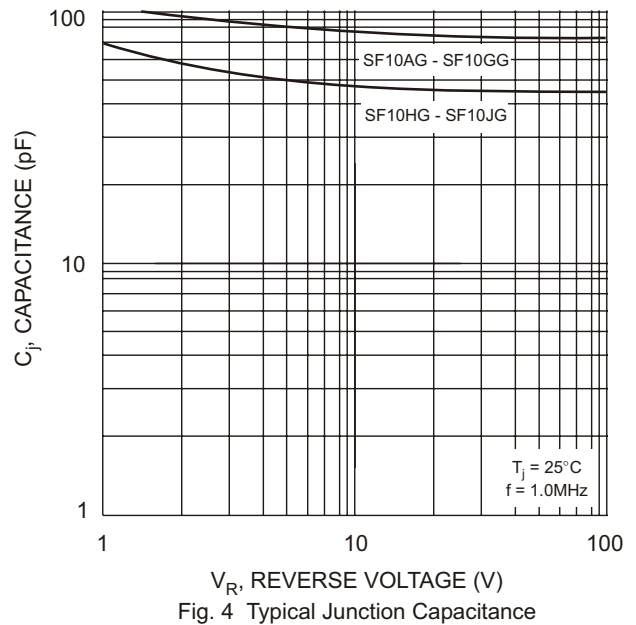
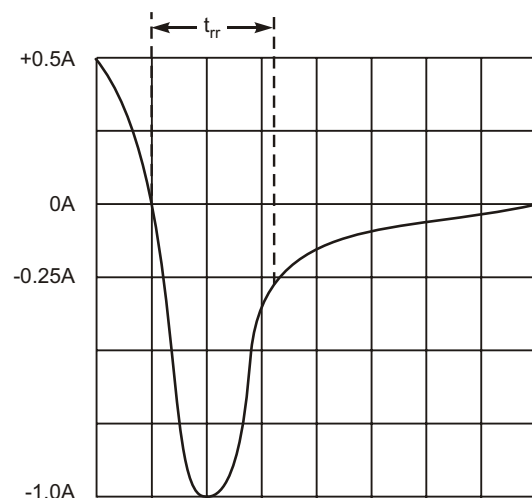


Fig. 4 Typical Junction Capacitance



Set time base for 50/100 ns/cm